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Fundamental design of hydrogen storage structures and systems.

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Fundamental simulations of hydrogen interactions with host structures offer indispensable insights to the understanding and design of hydrogen storage materials for practical applications. First-principles approaches were applied to selected materials of high promise, e.g., doped/defective carbon, doped hydrides and metal/amine complexes. Several candidates show large capacities for hydrogen – over the 6-9 mass-percentage threshold considered for applications. Recent progress on carbon nanostructures show the importance of defects and doping on extra hydrogen uptake, and a small change of C-C interspacing on the mode-switching of hydrogen sorption. Work on the molecular analogues of the basic structural unit of boron-nitride indicates that transition metal (TM) atom doping can boost both the gravimetric and thermodynamic capacities of hydrogen in these materials. The H₂ binding to the TM dopants is Kubas-like in nature, though the maximum binding capacity at the TM doped sites does not follow the 18-electron rule. Progress in the Li-N-H system shows that the N-Li bond is weaker than one of the N-H bonds in LiNH₂, and consequently LiNH₂ can dissociate into: Li⁺ and (NH₂)⁻, or (LiNH)⁻ and H⁺. Hence, NH₃ may evolve as a transient gas, if it is not sufficiently captured by a reactive component, e.g. LiH. Molecular dynamics calculations indicate that hydrogen deliveries are possible close to fuel-cell operation conditions. Comparison is also made with experiment where possible.